



IWDTF 2017

2017 International Workshop on
DIELECTRIC THIN FILMS FOR FUTURE ELECTRON
DEVICES
— SCIENCE AND TECHNOLOGY —

IWDTF Young Award

(Oral Presentation)

is presented to

Kenta Watanabe

for the paper co-authored with

Daiki Terashima, Mikito Nozaki, Takahiro Yamada, Satoshi Nakazawa,
Masahiro Ishida, Yoshiharu Anda, Tetsuzo Ueda, Akitaka Yoshigoe,
Takuji Hosoi, Takayoshi Shimura, Heiji Watanabe ,

entitled

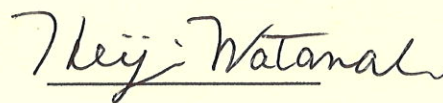
“SiO₂/AlON Stacked Gate Dielectrics for AlGaIn/GaN MOS-HFET”,

presented at 2017 International Workshop on

DIELECTRIC THIN FILMS FOR FUTURE ELECTRON DEVICES

— SCIENCE AND TECHNOLOGY —

November 20-22, 2017, Nara, Japan.



Heiji Watanabe
Chairperson
Organizing Committee

November 22, 2017